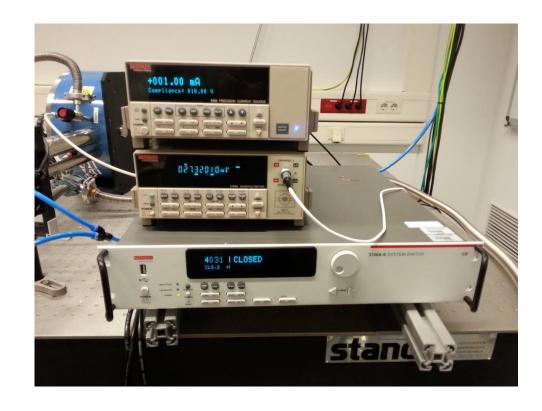
st MOKE a status upgrade

stMOKE:

Polarization rotation measures magnetization

new:

4 point DC resistance measurement option



baseline assumption:

axissymetric line source: $\phi(r) = \alpha \ln(r) + c$

=> sample of uniform thickness d

For a given current I entering at P and leaving at Q, The potential at e.g. R is given by

$$\phi(R) = -\frac{I\rho}{\pi d} \ln(\frac{a+b}{b})$$

=> van der Pauws theorem:

Furthermore: $R_{AB,CD} = R_{CD,AB}$

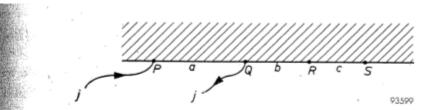


Fig. 4. A sample in the form of a semi-infinite plane with four contacts along its boundary for which eq. (1) is proved first.

L. J. van der Pauw

A method of measuring specific resistivity and Hall effect of discs of arbitrary shape. Philips Research Reports, Vol. 13, No.1 (1958)

$$\exp\left(-\pi R_{\text{AB,CD}} d/\varrho\right) + \exp\left(-\pi R_{\text{BC,DA}} d/\varrho\right) = 1,$$

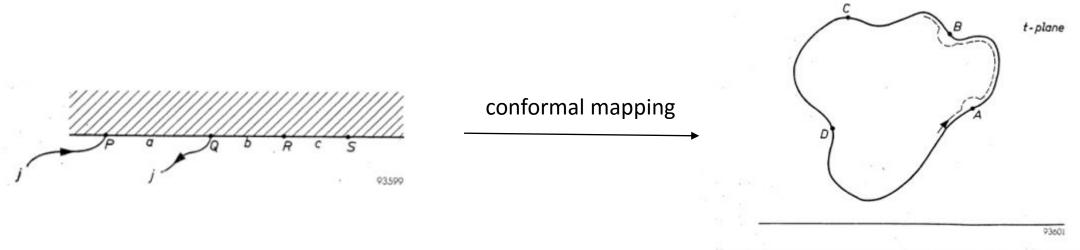
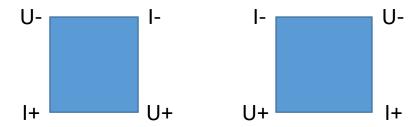


Fig. 6. A sample of arbitrary shape, lying in the complex t-plane.

$$f(z) = u(x,y) + i v(x,y)$$

$$\frac{d}{\rho} R_{AB, CD} \text{ invariant under such transformations}$$

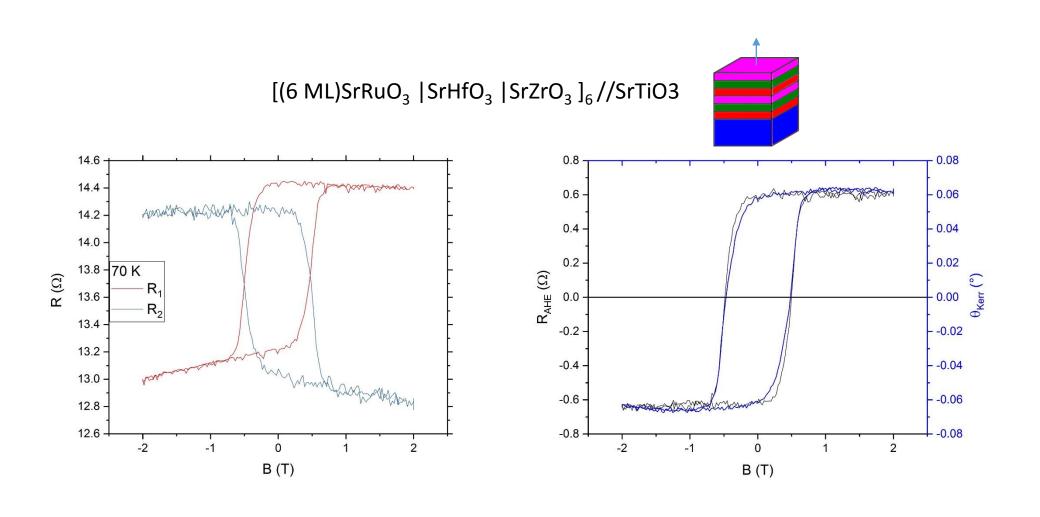


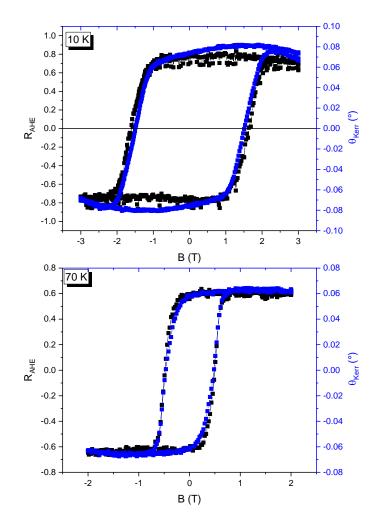
configuration 1

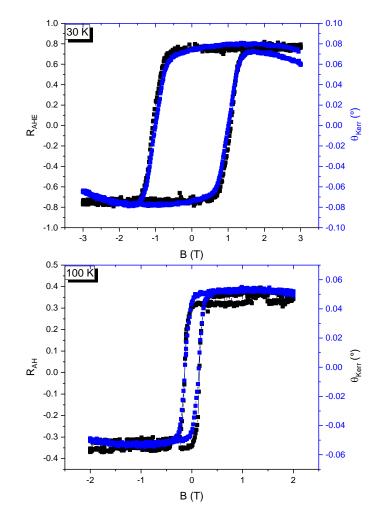
configuration 2

$$R_{1}(\underline{B},\underline{M}) = R_{0} + R_{\text{magneto}}(M) + R_{\text{hall}}(B_{\perp},M_{\perp}) \qquad R_{2}(\underline{B},\underline{M}) = R_{0} + R_{\text{magneto}}(M) - R_{\text{hall}}(B_{\perp},M_{\perp})$$

$$R_{Hall} = A_{NHE} H_z + A_{AHE} M_Z$$







Thank you for your attention